NSN 5961-01-256-4177



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-256-4177 **Inclosure Material:** Metal **Overall Length:** 1.330 inches **Function For Which Designed:** Switching **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.249 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

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